

20V Dual N-Channel HEXFET Power MOSFET in a SO-8 package; Similar to IRF8910TR with Lead Free Packaging

Manufacturers	Infineon Technologies Corporation
Package/Case	SOIC-8
Product Type	Transistors
RoHS	Green
Lifecycle	



Images are for reference only

Please submit RFQ for IRF8910TRPBF or [Email to us: sales@ovaga.com](mailto:sales@ovaga.com) We will contact you in 12 hours.

[RFQ](#)

General Description

RoHS Compliant

Low RDS(on)

Low RDS(ON) at 4.5V VGS

Ultra-Low Gate Impedance

Dual N-Channel MOSFET

Features

RoHS Compliant

Low RDS(on)

Low RDS(ON) at 4.5V VGS

Ultra-Low Gate Impedance

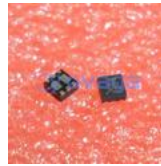
Dual N-Channel MOSFET

Related Products



[IRLTS6342TRPBF](#)

Infineon Technologies Corporation
TSOP-6



[IRLHS6376TRPBF](#)

Infineon Technologies Corporation
PQFN2x2DD



[IRF9310PBF](#)

Infineon Technologies Corporation
SOIC-8



[IRFH9310TRPBF](#)

Infineon Technologies Corporation
PQFN-8



[IRF9358TRPBF](#)

Infineon Technologies Corporation
SOP-8



[IRFB7430PBF](#)

Infineon Technologies Corporation
TO-220



[IRFB3307ZPBF](#)

Infineon Technologies Corporation
TO-220AB



[IRF7351TRPBF](#)

Infineon Technologies Corporation
SOIC-8